

NPN型 低频放大 小功率 贴片三极管 NPN Plastic-Encapsulate Transistors SMD	MMBT2222A 对应其他工业型号 2222A
<ul style="list-style-type: none"> ■ High breakdown voltage ■ Low collector-emitter saturation voltage ■ Transistor Polarity: NPN ■ Transistor pinout: BEC ■ SOT-23 Package ■ Marking Code: 1P 	

<p style="text-align: center;">Inner circuit</p>  <p style="text-align: center;">SOT-23 内部结构</p>	<p style="text-align: center;">MMBT2222A</p>  <p style="text-align: center;">SOT-23 管脚排列</p>	<p style="text-align: center;">元件标识 (打印)</p>  <p style="text-align: center;">DEVICE MARKING</p>
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CLASSIFICATION OF hFE

RANK	L	H
RANGE	100~200	200~300

MAXIMUM RATINGS

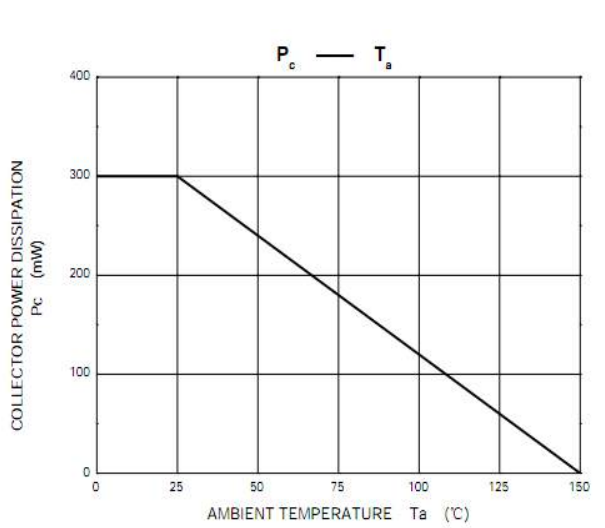
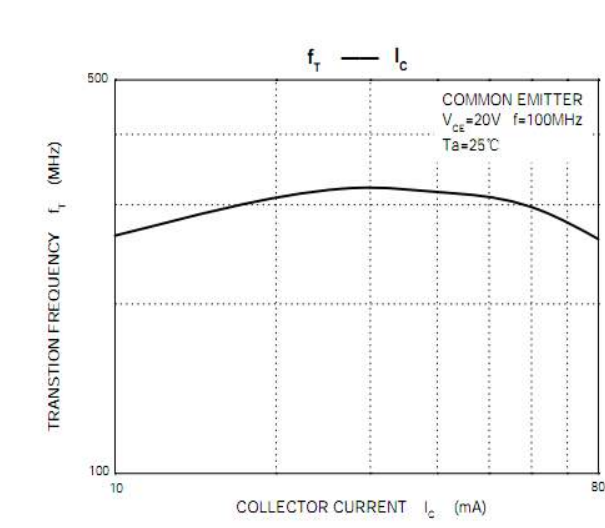
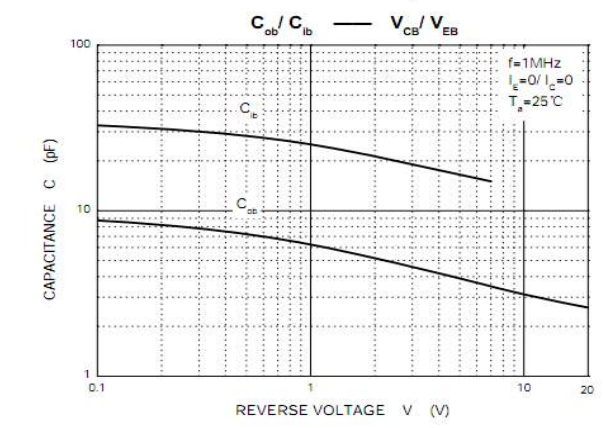
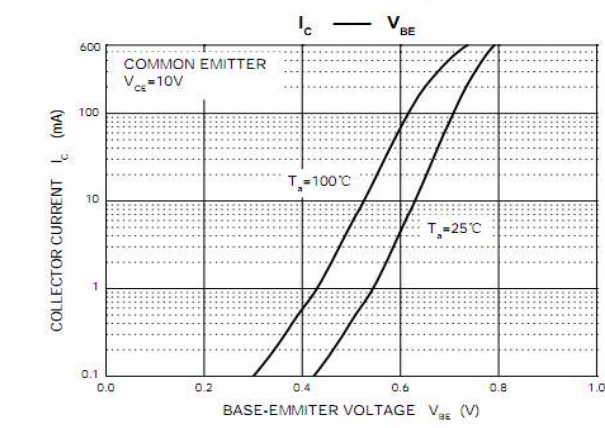
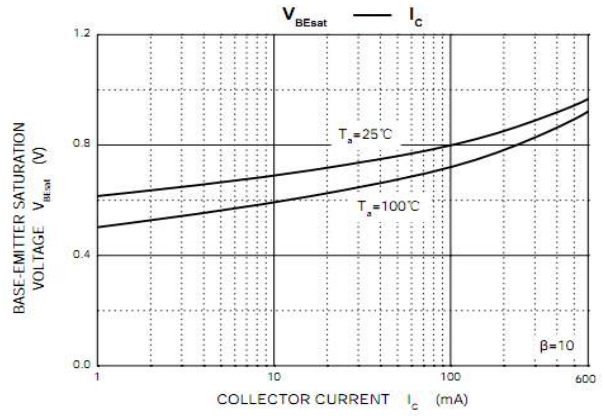
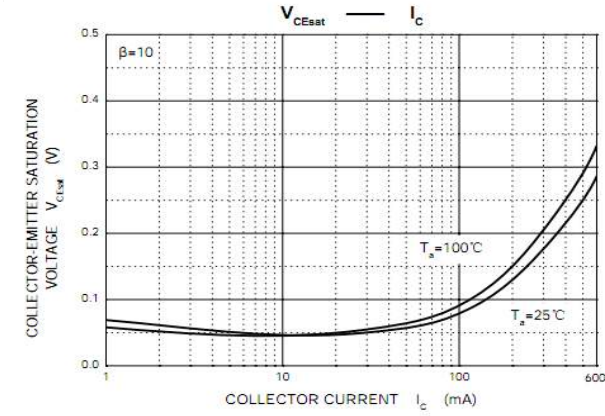
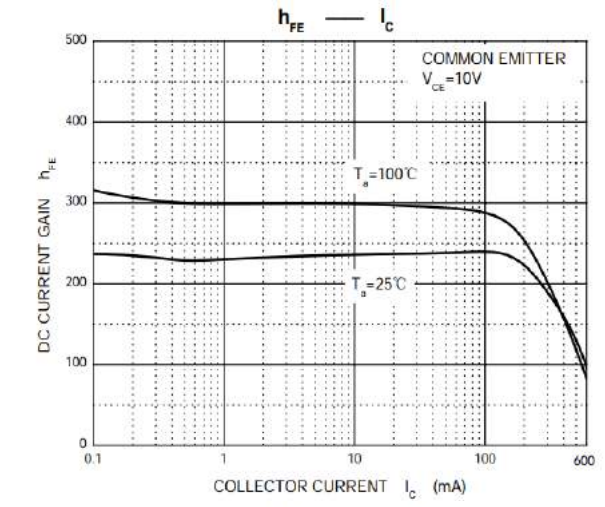
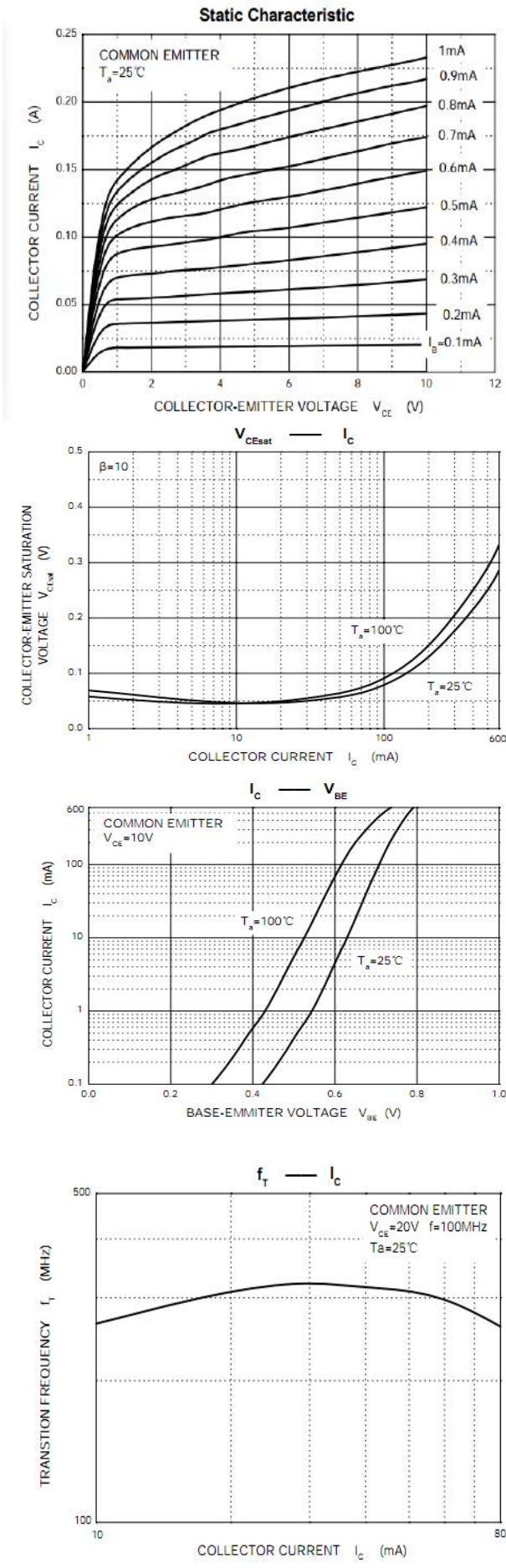
Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	75	V
V_{CEO}	Collector-Emitter Voltage	40	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current -Continuous	600	mA
P_C	Collector Dissipation	300	mW
R_{θJA}	Thermal Resistance, Junction to Ambient	417	°C/W
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

■ ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 10μA, I _E =0	75			V
Collector-emitter breakdown voltage	V _{(BR)CEO} *	I _C = 10mA, I _B =0	40			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =10μA, I _C =0	6			V
Collector cut-off current	I _{CBO}	V _{CB} =60V, I _E =0			0.01	μA
Collector cut-off current	I _{CEX}	V _{CE} =30V, V _{BE(off)} =3V			0.01	μA
Emitter cut-off current	I _{EBO}	V _{EB} = 3V, I _C =0			0.1	μA
DC current gain	h _{FE(1)} *	V _{CE} =10V, I _C = 150mA	100		300	
	h _{FE(2)}	V _{CE} =10V, I _C = 0.1mA	40			
	h _{FE(3)} *	V _{CE} =10V, I _C = 500mA	42			
Collector-emitter saturation voltage	V _{CE(sat)} *	I _C =500 mA, I _B = 50mA I _C =150 mA, I _B =15mA			1 0.3	V
Base-emitter saturation voltage	V _{BE(sat)} *	I _C =500 mA, I _B = 50mA I _C =150 mA, I _B =15mA			2.0 1.2	V
Transition frequency	f _T	V _{CE} =20V, I _C = 20mA, f=100MHz	300			MHz
Delay time	t _d	V _{CC} =30V, V _{BE(off)} =-0.5V			10	ns
Rise time	t _r	I _C =150mA, I _{B1} = 15mA			25	ns
Storage time	t _s	V _{CC} =30V, I _C =150mA			225	ns
Fall time	t _f	I _{B1} =-I _{B2} =15mA			60	ns

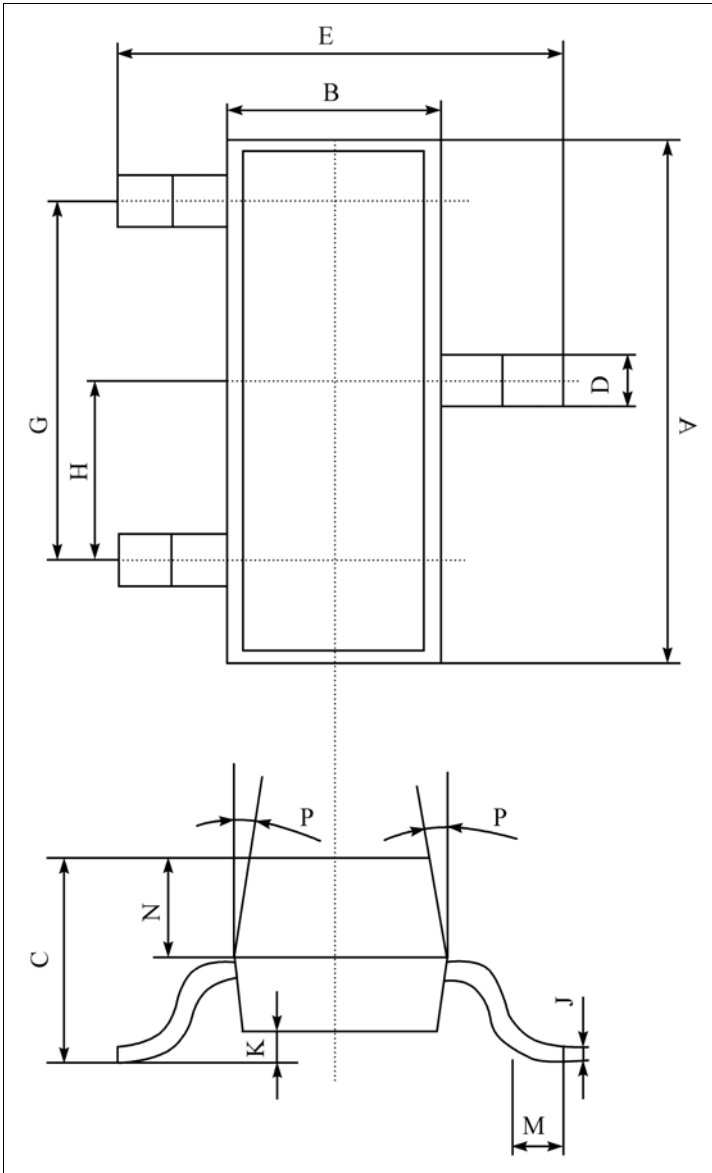
*pulse test: Pulse Width ≤300μs, Duty Cycles ≤ 2.0%.

TYPICAL CHARACTERISTICS



■ DIMENSION

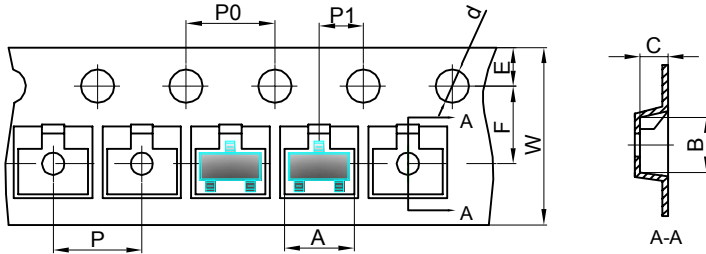
单位 (UNIT) : mm



序号	数值及公差
A	2.90±0.10
B	1.30±0.10
C	1.00±0.10
D	0.40±0.10
E	2.40±0.20
G	1.90±0.10
H	0.95±0.05
J	0.13±0.05
K	0.00-0.10
M	≥0.20
N	0.60±0.10
P	7±2°

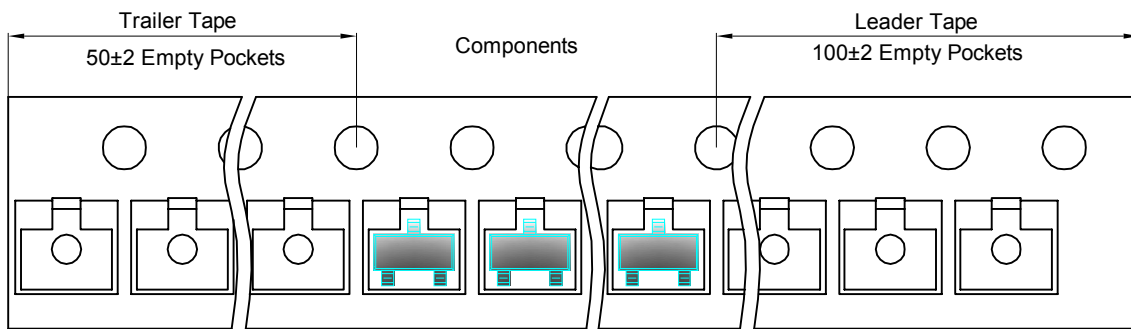
Packing
SOT-23 包装规格
SMD片式表面贴封装
包装方式: 载带卷盘包装
Tape & Reel, 3Kpcs/Reel
每卷数量3000只 (3Kpcs/Reel)
每盒数量45000只 (45Kpcs/BOX)
每箱数量180000只 (180Kpcs/Cartons)

SOT-23 Embossed Carrier Tape

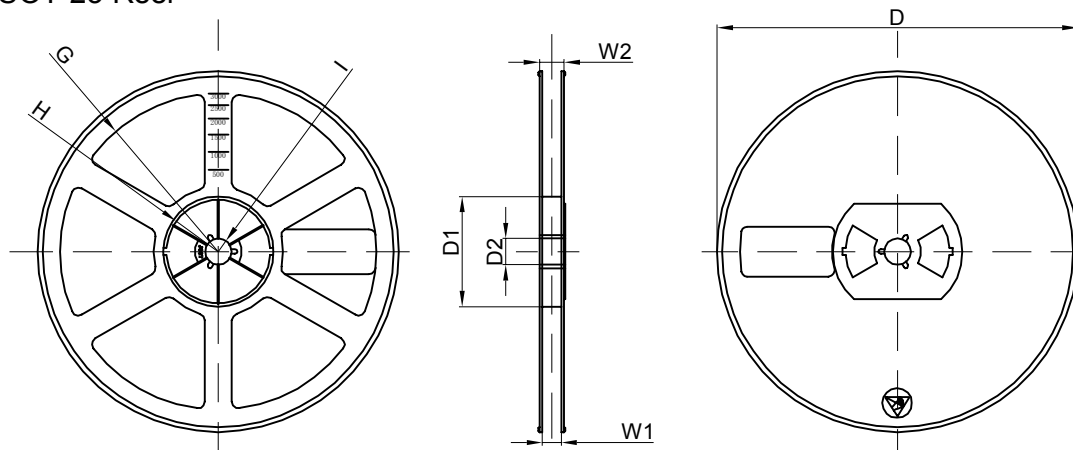


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23 Tape Leader and Trailer



SOT-23 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	45,000 pcs	192×192×193	180,000 pcs	404×404×214	